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| <input type="checkbox"/> | <p>2. <b>Generation of plasma emission from porous silicon</b><br/> Tam, H.L.; Kung, E.W.; Zhang, X.X.; Gong, M.L.; Cheah, K.W.;<br/> Optoelectronics, Proceedings of the Sixth Chinese Symposium<br/> 12-14 Sept. 2003 Page(s):120 - 123<br/> Digital Object Identifier 10.1109/COS.2003.1278180<br/> <a href="#">AbstractPlus</a>   Full Text: <a href="#">PDF</a>(314 KB) IEEE CNF</p>                                                                                               |
| <input type="checkbox"/> | <p>3. <b>One order of magnitude increase in quantum efficiency of PtSi/Si IR detectors</b><br/> Raissi, F.; Far, M.M.;<br/> Microelectronics, 2000. ICM 2000. Proceedings of the 12th International Conference on<br/> 31 Oct.-2 Nov. 2000 Page(s):321 - 323<br/> Digital Object Identifier 10.1109/ICM.2000.916469<br/> <a href="#">AbstractPlus</a>   Full Text: <a href="#">PDF</a>(284 KB) IEEE CNF</p>                                                                             |
| <input type="checkbox"/> | <p>4. <b>Improvement of <math>\beta</math>-SiC/Si pn diode high temperature characteristics with porous silicon layer</b><br/> Wen-Tse Hsieh; Yean-Kuen Fang; Lee, W.J.; Chi-Wei Ho; Kuen-Hsien Wu; Jyh-Jier Ho; Jun-Dar H<br/> Electronics Letters<br/> Volume 36, Issue 1, 6 Jan. 2000 Page(s):86 - 87<br/> Digital Object Identifier 10.1049/el:20000019<br/> <a href="#">AbstractPlus</a>   Full Text: <a href="#">PDF</a>(116 KB) IEE JNL</p>                                      |
| <input type="checkbox"/> | <p>5. <b>Visible electroluminescence from stain-etched porous Si diodes</b><br/> Xu, J.; Steckl, A.J.;<br/> Electron Device Letters, IEEE<br/> Volume 15, Issue 12, Dec. 1994 Page(s):507 - 509<br/> Digital Object Identifier 10.1109/55.338419<br/> <a href="#">AbstractPlus</a>   Full Text: <a href="#">PDF</a>(248 KB) IEEE JNL</p>                                                                                                                                                |
| <input type="checkbox"/> | <p>6. <b>Progress toward nanoscale silicon light emitters</b></p>                                                                                                                                                                                                                                                                                                                                                                                                                       |

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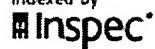
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